

# Manipulation of photoluminescence of two-dimensional MoSe<sub>2</sub> by gold nanoantennas

## *Supplementary Information*

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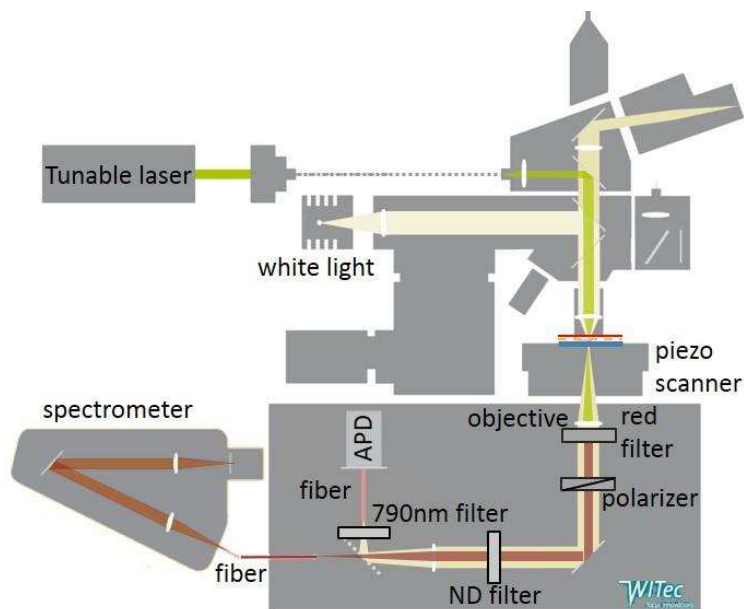
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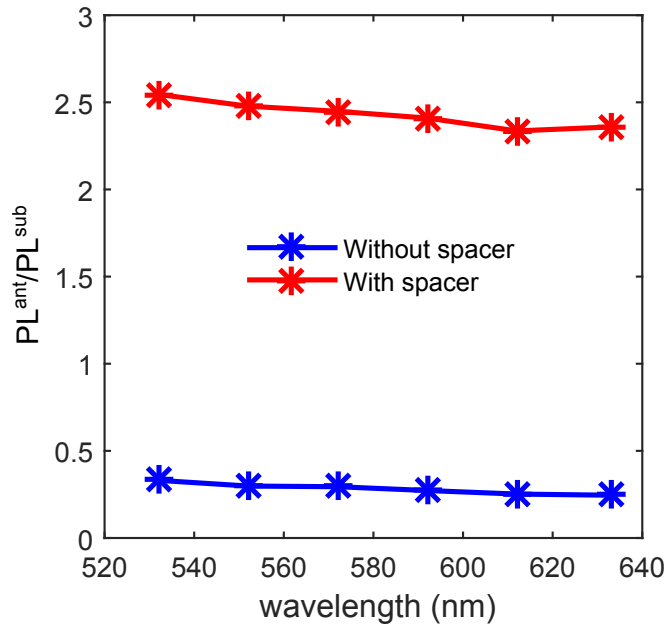
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The photoluminescence (PL) of the samples were measured by commercial WiTec - alpha300S system in confocal microscope configuration, the setup of this system is shown in Figure S1.



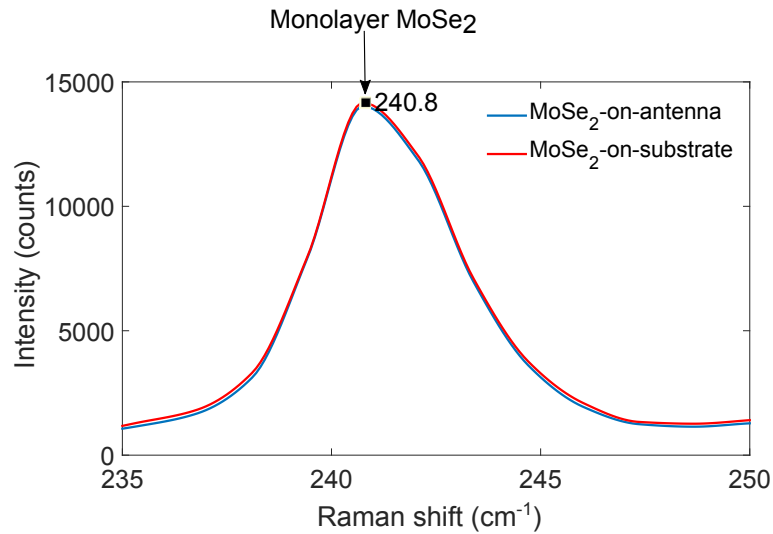
**Figure S1.** Photoluminescence measurement setup. The tunable laser covers a long wavelength range which enables us to change the excitation wavelength from 532 nm to 633 nm. The 790 nm filter generally refers to filters that pass wavelength around 790 nm while blocking the excitation wavelength, we used either a longpass filter cut at 630 nm or a 633 nm notch filter which blocks the excitation laser.

To verify that excitation enhancement does not affect our results much, we measured the enhancement (quenching) effect with varying wavelength under same power, Figure S2 shows enhancement (quenching) effect dependence on excitation wavelength. The results here show that the enhancement (quenching) effect do not depend on excitation wavelength verifying that excitation does not contribute to the enhancement we observed here.



**Figure S2.** Antenna effects varying with excitation wavelength for both samples with a collection polarization along the gold particle long axis.

To confirm that the MoSe<sub>2</sub> flakes we used in experiments are monolayers, we also conducted Raman measurements. The Raman signal from two different parts of our sample are shown in Figure S3. The observed Raman peak at 240.8 cm<sup>-1</sup> is consistent with results reported in Refs.<sup>1,2</sup> for monolayer MoSe<sub>2</sub>, thus indicating that the flakes we used are monolayers. On the other hand, the results in the literature show that the exact Raman peak of a monolayer can vary depending on the crystal quality and the method of exfoliation. Furthermore, the bilayer MoSe<sub>2</sub> Raman peak is relatively close to monolayer's (only different by 1~2 cm<sup>-1</sup>).<sup>1,2</sup> Therefore, the Raman signal could not exactly identify the number of layers of the MoSe<sub>2</sub> flakes. However, combined with the PL spectrum, shown in main text, we could conclude that the flakes we used in experiments are indeed monolayer MoSe<sub>2</sub>.



**Figure S3.** Raman signal of our MoSe<sub>2</sub> flake sample on different regions. Here we use 532 nm laser for excitation (laser power of around 280  $\mu$ w), the signal is collected by 100x objective with numerical aperture of 0.9 and analysed by a grating spectrometer with 2400 1/mm. The original data resolution is not enough to give the exact peak position, the above curves are fitted by Piecewise cubic Hermite interpolation which preserves the shape of the curve well.

## References

1. Tonndorf, P. *et al.* Photoluminescence emission and Raman response of monolayer MoS<sub>2</sub>, MoSe<sub>2</sub>, and WSe<sub>2</sub>. *Opt. Express* **21**, 4908–4916 (2013). [1208.5864](#).
2. Tongay, S. *et al.* Thermally Driven Crossover from Indirect toward Direct Bandgap in 2D Semiconductors: MoSe<sub>2</sub> versus MoS<sub>2</sub>. *Nano Lett.* **12**, 5576–5580 (2012).